## NSN 5961-01-204-1481

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View Online at https://aerobasegroup.com/nsn/5961-01-204-1481 **Inclosure Material:** Metal **Overall Length:** 1.375 inches **Overall Height:** Between 0.562 inches and 0.612 inches Overall Width: 1.050 inches **End Application:** B1b aircraft **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.0 emitter to base voltage, dc and 1200.0 collector to emitter saturation voltage and 850.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 40.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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